

# V<sub>BUS</sub> Directly Powered, High Speed USB 2.0 (480Mbps) DPDT Analog Switch

### **GENERAL DESCRIPTION**

The SGM7226 is a DPDT (double-pole/double-throw) analog switch. It operates from a 1.8V to 5.5V single power supply and can be powered directly by  $V_{BUS}$ . Each switch of the SGM7226 is bidirectional, which can ensure that the high speed signals have little or no attenuation at the outputs.

The SGM7226 features high speed, low power and wide bandwidth. The high performances make it very suitable for multiple applications, such as cellular phones and computer peripherals, etc.

The SGM7226 has a power-off protection. It can prevent accidental signal leakage and ensure system reliability under power-down and over-voltage conditions. In addition, the device is capable of withstanding a  $V_{\text{BUS}}$  short to D+ or D- when the device is either powered on or powered off due to the special circuitry on the D+/D- pins.

The SGM7226 is available in a Green TQFN-2.6×1.8-16L package. It operates over an ambient temperature range of -40°C to +85°C.

### **FEATURES**

- Supply Voltage Range: 1.8V to 5.5V
- V<sub>BUS</sub> Directly Power
- On-Resistance: 5Ω (TYP)
- High Off-Isolation: -35dB ( $R_L = 50\Omega$ , f = 250MHz)
- Low Crosstalk: -30dB ( $R_L = 50\Omega$ , f = 250MHz)
- -3dB Bandwidth: 550MHz
- Fast Switching Times at V<sub>CC</sub> = 5V:

 $t_{ON}$  = 15ns (TYP)  $t_{OFF}$  = 20ns (TYP)

- Break-Before-Make Switching
- Power-Off and Power-On Protections
- -40°C to +85°C Operating Temperature Range
- Available in a Green TQFN-2.6×1.8-16L Package

### **APPLICATIONS**

Cellular Phones

**Digital Cameras** 

Portable Equipment

Computer Peripherals

**Battery-Powered Systems** 

Routes Signals for USB 2.0 Full-Speed

# PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM7226	TQFN-2.6×1.8-16L	-40°C to +85°C	SGM7226YTQA16G/TR	7226 XXXXX	Tape and Reel, 3000

#### MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.

XXXXX = Date Code and Vendor Code.

Vendor Code
Date Code - Week

- Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

### **ABSOLUTE MAXIMUM RATINGS**

V <sub>CC</sub> to GND	0V to 6.0V
V <sub>SET</sub>	0.3V to 5.5V
OE, S, HSDn+, HSDn-, D+, D	0.3V to 3.3+0.3V
Continuous Current HSDn or Dn	±50mA
Peak Current HSDn or Dn	±100mA
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	8000V
MM	400V

### RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range	1.8V to 5.5V
Operating Temperature Range	40°C to +85°C

### **OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

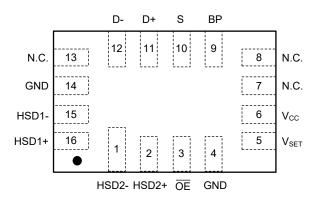
### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



# **PIN CONFIGURATION**



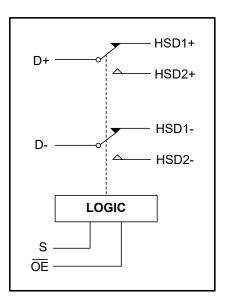


TQFN-2.6×1.8-16L

# **PIN DESCRIPTION**

PIN	NAME	FUNCTION
1,2	HSD2-, HSD2+	
15, 16	HSD1-, HSD1+	Data Ports.
11, 12	D+, D-	
3	ŌĒ	Output Enable Control Pin.
4, 14	GND	Ground.
5	V <sub>SET</sub>	Internal Used Pin. It is recommended to connect a $10k\Omega$ resistor between $V_{SET}$ pin and $V_{CC}$ pin.
6	V <sub>CC</sub>	Positive Power Supply Pin.
7, 8, 13	N.C.	No Connect.
9	BP	Internal Voltage Reference Decoupling Pin. A 2.2µF ceramic capacitor must be used to provide enough decoupling. Connect the capacitor between BP pin and GND.
10	S	Select Input Pin.

# **BLOCK DIAGRAM**



# **FUNCTION TABLE**

ŌĒ	S	HSD1+, HSD1-	HSD2+, HSD2-
0	0	ON	OFF
0	1	OFF	ON
1	X	OFF	OFF

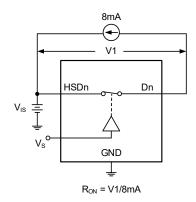
X = Don't care.

# **ELECTRICAL CHARACTERISTICS**

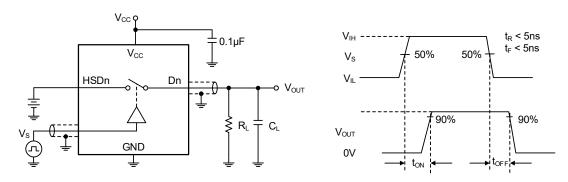
( $V_{CC}$  = +5.0V,  $T_A$  = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Analog Switch			•	•	•	•	
Analog I/O Voltage (D+, D-, HSD1+, HSD1-, HSD2+, HSD2-)	V <sub>IS</sub>		0		3.3	V	
On-Resistance	$R_{\text{ON}}$	$V_{IS}$ = 0V to 0.4V, $I_D$ = 8mA, Test Circuit 1		5	6.5	Ω	
On-Resistance Match between Channels	$\Delta R_{\text{ON}}$	$V_{IS}$ = 0V to 0.4V, $I_{D}$ = 8mA, Test Circuit 1		0.35	0.6	Ω	
On-Resistance Flatness	R <sub>FLAT(ON)</sub>	$V_{IS}$ = 0V to 1.0V, $I_D$ = 8mA, Test Circuit 1		0.6	1	Ω	
Power Off Leakage Current (D+, D-)	I <sub>OFF</sub>	$V_{CC} = 0V$ , $V_{D} = 0V$ to 3.6V, $V_{S}$ , $V_{\overline{OE}} = 0V$ or 3.6 V			1	μA	
Source Off Leakage Current	I <sub>HSD2(OFF)</sub> , I <sub>HSD1(OFF)</sub>	V <sub>IS</sub> = 3.3V/0.3V, V <sub>D</sub> = 0.3V/3.3V			1	μΑ	
Channel On Leakage Current	I <sub>HSD2(ON)</sub> , I <sub>HSD1(ON)</sub>	$V_{IS} = 3.3V/0.3V$ , $V_{D} = 3.3V/0.3V$ or floating			1	μΑ	
Digital Inputs	, ,						
Input High Voltage	$V_{IH(S,\ \overline{OE})}$		1.5		3.3	V	
Input High Voltage	V <sub>IH (VSET)</sub>		1.5		5.5	]	
Input Low Voltage	V <sub>IL</sub>				0.35	V	
Input Leakage Current	$I_{IN(S,\ \overline{OE})}$				1	μA	
	I <sub>IN ((VSET)</sub>				1.5	<u>'</u>	
Dynamic Characteristics			1	T		,	
Turn-On Time	t <sub>ON</sub>	$V_{IS} = 0.8V$ , $R_L = 50\Omega$ , $C_L = 10pF$ ,		15		ns	
Turn-Off Time	t <sub>OFF</sub>	Test Circuit 2		20		ns	
Break-Before-Make Time Delay	$t_{D}$	$V_{IS}$ = 0.8V, $R_L$ = 50 $\Omega$ , $C_L$ = 10pF, Test Circuit 3		3.5		ns	
Propagation Delay	$t_{PD}$	$R_L = 50\Omega$ , $C_L = 10pF$		0.5		ns	
Off Isolation	O <sub>ISO</sub>	Signal = 0dBm, $R_L$ = 50 $\Omega$ , f = 250MHz, Test Circuit 4		-35		dB	
Channel-to-Channel Crosstalk	X <sub>TALK</sub>	Signal = 0dBm, $R_L$ = 50 $\Omega$ , $f$ = 250MHz, Test Circuit 5		-30		dB	
-3dB Bandwidth	BW	Signal = 0dBm, $R_L = 50\Omega$ , $C_L = 5pF$ , Test Circuit 6		550		MHz	
Channel-to-Channel Skew	t <sub>SKEW</sub>	$R_L = 50\Omega$ , $C_L = 10pF$		1.5		ns	
Charge Injection Select Input to Common I/O	Q	$V_G$ = GND, $C_L$ = 1.0nF, $R_G$ = 0 $\Omega$ , $Q$ = $C_L$ × $V_{OUT}$ , Test Circuit 7		10		рС	
HSD+, HSD-, D+, D-		f = 1MHz		10		pF	
ON Capacitance	Con	f = 250MHz		15		þΓ	
Power Requirements							
Power Supply Range	V <sub>CC</sub>		1.8		5.5	V	
Power Supply Current	I <sub>cc</sub>			20	30	μΑ	

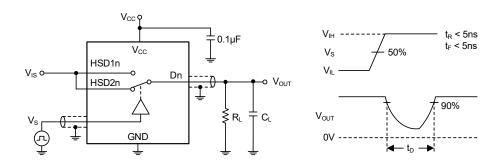
# **TEST CIRCUITS**



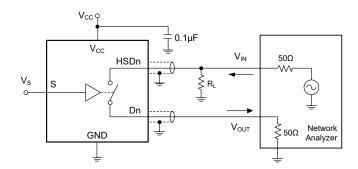
Test Circuit 1. On-Resistance



Test Circuit 2. Switching Times (ton, toff)



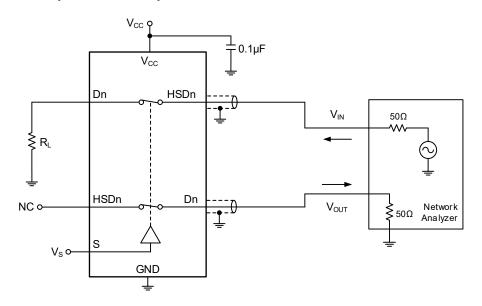
Test Circuit 3. Break-Before-Make Time (t<sub>D</sub>)



**Test Circuit 4. Off Isolation** 

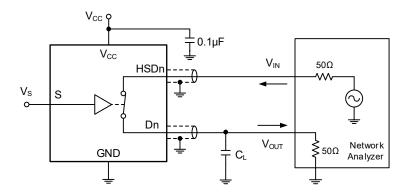


# **TEST CIRCUITS (continued)**

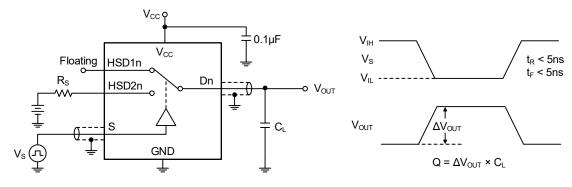


Channel-to-Channel Crosstalk = -20 log ( $V_{HSDn}/V_{OUT}$ )

Test Circuit 5. Channel-to-Channel Crosstalk



Test Circuit 6. -3dB Bandwidth



Test Circuit 7. Charge Injection (Q)



# **APPLICATION INFORMATION**

### **Power-Off Protection**

When D+ or D- is shorted to  $V_{BUS}$ , there is a special protection circuit inside the SGM7226, so that the device will not be damaged within 24 hours. In case of power-down or over-voltage event, the protection circuit can prevent the leakage signal on D+/D- pins to ensure the reliability of the system.

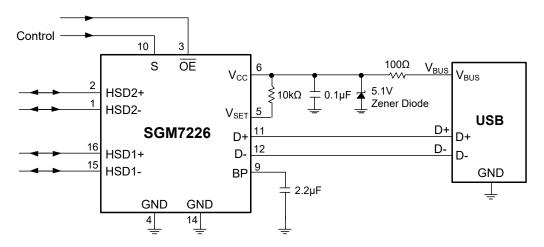
#### **Power-On Protection**

The USB 2.0 specification requires USB device to ensure that the device will not be damaged even if  $V_{\text{BUS}}$  short-circuit occurs during data transmission. Therefore,

under over-voltage conditions, the SGM7226 will limit the current flowing back to the  $V_{\text{CC}}$  track, and the current will not exceed the safe operating range.

### **Application Circuit**

The application circuit is shown in Figure 1. If SGM7226 is powered from  $V_{BUS}$ , a 5.1V Zener diode is recommended to be used to suppress the voltage spike in  $V_{BUS}$  power line generated by USB interface hot-insertion.



**Figure 1. Application Circuit** 

### **REVISION HISTORY**

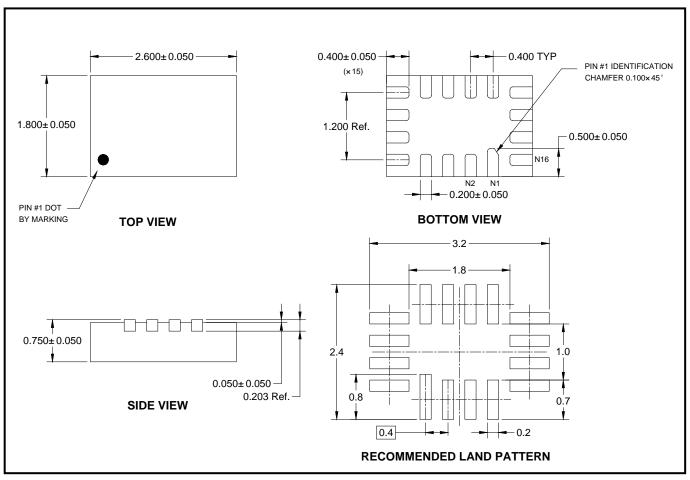
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

MAY 2016 - REV.A to REV.A.1	Page
Changed Package Outline Dimensions of TQFN-2.6×1.8-16L to TX00078.001	10
Changed Key Parameter List of Tape and Reel	11
Changes from Original (OCTOBER 2014) to REV.A	Page
Changed from product preview to production data	All



# PACKAGE OUTLINE DIMENSIONS

# TQFN-2.6×1.8-16L

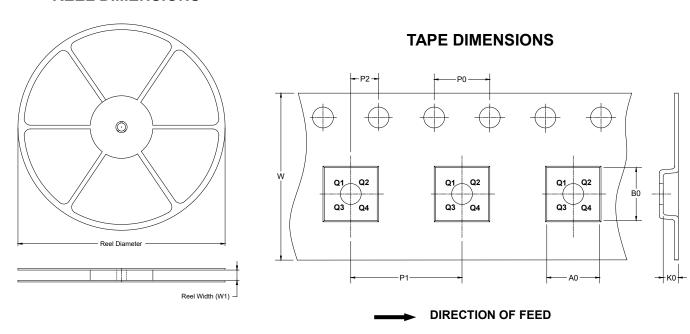


#### NOTES

- 1. All linear dimensions are in millimeters.
- 2. This drawing is subject to change without notice.

# TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**

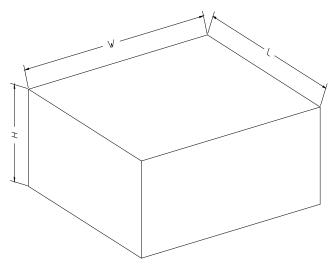


NOTE: The picture is only for reference. Please make the object as the standard.

### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TQFN-2.6×1.8-16L	7"	9.0	2.01	2.81	0.93	4.0	4.0	2.0	8.0	Q1

### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18